

**TECHNICAL DATA**  
**DATA SHEET 4547, REV. B**

**HERMETIC POWER SCHOTTKY RECTIFIER**  
**Very Low Forward Voltage Drop**

**Applications:**

- Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

**Features:**

- Very Low Forward Voltage Drop
- High Efficiency
- High Frequency Application
- Guard Ring for Enhanced Durability and Long Term Reliability

**MAXIMUM RATINGS**

ALL RATINGS ARE @  $T_C = 25^\circ\text{C}$  UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	60	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$ )	$I_o$	75	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ( $t=8.3\text{ms}$ , Sine)	$I_{FSM}$	500	Amps
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	1.07	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	$T_{op}$	-65 to + 175	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	$T_{stg}$	-65 to + 175	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS**

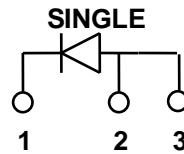
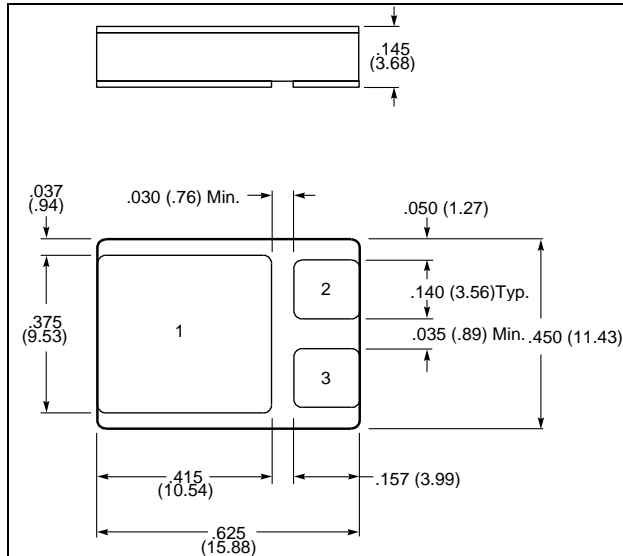
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ( $I_f = 75$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$V_f$	0.82 0.70	Volts
MAXIMUM REVERSE CURRENT ( $I_r$ @ 60V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$I_r$	1 275	mA
MAXIMUM JUNCTION CAPACITANCE ( $V_r=5\text{V}$ )	$C_T$	2200	pF

SENSITRON

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## MECHANICAL DIMENSIONS: in Inches / mm

**SMD-1**

## PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE

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